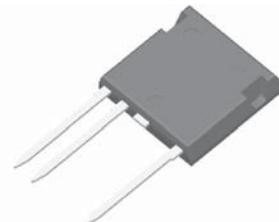
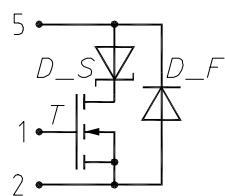


CoolMOS Power MOSFET with Series Schottky Diode and Ultra Fast Antiparallel Diode in High Voltage ISOPLUS i4-PAC™

I_{D25} = 38 A
 V_{DSS} = 600 V
 R_{DSon} = 60 mΩ
 t_{rr} = 70 ns

COOLMOS
Power Semiconductors



MOSFET T

| Symbol | Conditions | Maximum Ratings | | |
|---|---|--|------|----------------------|
| V_{DSS} | $T_{VJ} = 25^\circ\text{C}$ to 150°C | 600 | V | |
| V_{GS} | | ± 20 | V | |
| I_{D25} | $T_c = 25^\circ\text{C}$ | 38 | A | |
| I_{D90} | $T_c = 90^\circ\text{C}$ | 25 | A | |
| Symbol | Conditions | Characteristic Values ($T_{VJ} = 25^\circ\text{C}$, unless otherwise specified) | | |
| | | min. | typ. | max. |
| R_{DSon} | $V_{GS} = 10 \text{ V}; I_D = I_{D90}$ | 60 | 70 | mΩ |
| V_{GSth} | $V_{DS} = 20 \text{ V}; I_D = 3 \text{ mA}$ | 3.5 | | V |
| I_{DSS} | $V_{DS} = V_{DSS}; V_{GS} = 0 \text{ V}; T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$ | | 0.3 | mA |
| I_{GSS} | $V_{GS} = \pm 20 \text{ V}; V_{DS} = 0 \text{ V}$ | | 100 | nA |
| Q_g Q_{gs} Q_{gd} | $V_{GS} = 10 \text{ V}; V_{DS} = 350 \text{ V}; I_D = 50 \text{ A}$ | 220 55 125 | | nC nC nC |
| $t_{d(on)}$ t_r $t_{d(off)}$ t_f | $V_{GS} = 10 \text{ V}; V_{DS} = 380 \text{ V};$ $I_D = 25 \text{ A}; R_G = 1.8 \Omega$ | 30 95 100 10 | | ns ns ns ns |
| R_{thJC} R_{thJH} | with heat transfer paste | 0.9 | 0.45 | K/W K/W |

Features

- fast CoolMOS power MOSFET - 2nd generation
 - High blocking voltage
 - Low on resistance
 - Low thermal resistance due to reduced chip thickness
- Series Schottky diode prevents current flow through MOSFET's body diode
 - very low forward voltage
 - fast switching
- Ultra fast HiPerFRED™ anti parallel diode
 - low operating forward voltage
 - fast and soft reverse recovery - low switching losses
- ISOPLUS i4-PAC™ high voltage package
 - isolated back surface
 - low coupling capacity between pins and heatsink
 - enlarged creepage towards heatsink
 - enlarged creepage between high voltage pins
 - application friendly pinout
 - high reliability
 - industry standard outline

Applications

Converters with

- circuit operation leading to current flow through switches in reverse direction - e. g.
 - phaseleg with inductive load
 - resonant circuits
- high switching frequency

Examples

- switched mode power supplies (SMPS)
- uninterruptable power supplies (UPS)
- DC-DC converters
- welding converters
- converters for inductive heating
- drive converters

Series Schottky Diode D_S

| Symbol | Conditions | Maximum Ratings | | |
|------------------|-----------------------|-----------------|---|--|
| I _{F25} | T _C = 25°C | 60 | A | |
| I _{F90} | T _C = 90°C | 40 | A | |

| Symbol | Conditions | Characteristic Values | | | |
|--|--|--|------|------|------|
| | | (T _{VJ} = 25°C, unless otherwise specified) | min. | typ. | max. |
| V _F | I _F = 20 A; T _{VJ} = 25°C T _{VJ} = 125°C | 0.7 | 0.9 | V | V |
| R _{thJC} R _{thJH} | with heat transfer paste | 2.9 | 2 | K/W | K/W |

Anti Parallel Diode D_F

| Symbol | Conditions | Maximum Ratings | | |
|------------------|-----------------------|-----------------|---|--|
| I _{F25} | T _C = 25°C | 32 | A | |
| I _{F90} | T _C = 90°C | 16 | A | |

| Symbol | Conditions | Characteristic Values | | | |
|--|--|--|------|------|------|
| | | (T _{VJ} = 25°C, unless otherwise specified) | min. | typ. | max. |
| V _F | I _F = 20 A; T _{VJ} = 25°C T _{VJ} = 125°C | 2.1 | 2.5 | V | V |
| t _{rr} | { I _F = 30 A; di _F /dt = -500 A/μs; T _{VJ} = 125°C V _R = 600 V; V _{GE} = 0 V | 15 | 70 | A | ns |
| R _{thJC} R _{thJH} | with heat transfer paste | 2.6 | 1.3 | K/W | K/W |

Component

| Symbol | Conditions | Maximum Ratings | | |
|-------------------|------------------------------------|-----------------|----|--|
| V _{ISOL} | I _{ISOL} ≤ 1 mA; 50/60 Hz | 2500 | V~ | |
| T _{VJ} | | -40...+150 | °C | |
| T _{stg} | | -40...+125 | °C | |
| F _c | mounting force with clip | 20 ... 120 | N | |

| Symbol | Conditions | Characteristic Values | | |
|--|---|-----------------------|------|----------|
| | | min. | typ. | max. |
| C _p | coupling capacity between shorted pins and mounting tab in the case | 40 | | pF |
| d _s , d _A d _s , d _A | D pin - S pin pin - backside metal | 7 5.5 | | mm mm |
| Weight | | 9 | | g |

Dimensions in mm (1 mm = 0.0394")